NSN 5961-00-955-9891

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View Online at https://aerobasegroup.com/nsn/5961-00-955-9891 **Inclosure Material:** Metal **Overall Length:** 0.400 inches **Overall Diameter:** 0.768 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector-to-base, emitter open and 60.0 breakdown voltage, collector-to-emitter, base open and 10.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 3.00 amperes source cutoff current and 6.00 amperes source cutoff current **Power Rating Per Characteristic:** 75.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius case **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: